# DSC2P01

### Silicon NPN epitaxial planar type

For low frequency amplification Darlington connection

#### ■ Features

- $\bullet$  High forward current transfer ratio  $h_{FE}$  with excellent linearity
- Halogen-free / RoHS compliant (EU RoHS / UL-94 V-0 / MSL: Level 1 compliant)

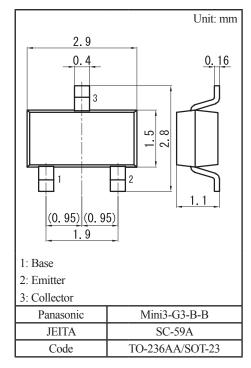
#### ■ Marking Symbol: E5

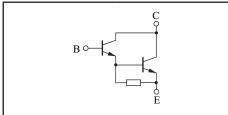
#### ■ Packaging

DSC2P01×0L Embossed type (Thermo-compression sealing): 3 000 pcs / reel (standard)

#### ■ Absolute Maximum Ratings $T_a = 25$ °C

Parameter	Symbol Rating		Unit	
Collector-base voltage (Emitter open)	V <sub>CBO</sub>	60	V	
Collector-emitter voltage (Base open)	V <sub>CEO</sub>	50	V	
Emitter-base voltage (Collector open)	V <sub>EBO</sub>	5	V	
Collector current	$I_{C}$	500	mA	
Peak collector current	I <sub>CP</sub>	750	mA	
Total power dissipation	P <sub>T</sub>	200	mW	
Junction temperature	T <sub>j</sub>	150	°C	
Operating ambient temperature	T <sub>opr</sub>	-40 to +85	°C	
Storage temperature	T <sub>stg</sub>	-55 to +150	°C	





#### ■ Electrical Characteristics $T_a = 25$ °C±3°C

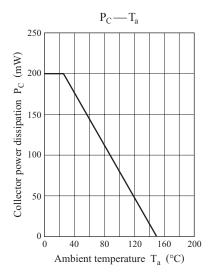
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector-base voltage (Emitter open)	$V_{CBO}$	$I_C = 100 \mu\text{A}, I_E = 0$	60			V
Collector-emitter voltage (Base open)	V <sub>CEO</sub>	$I_{\rm C} = 1 \text{ mA}, I_{\rm B} = 0$	50			V
Emitter-base voltage (Collector open)	$V_{\mathrm{EBO}}$	$I_E = 100  \mu A, I_C = 0$	5			V
Collector-base cutoff current (Emitter open)	$I_{CBO}$	$V_{CB} = 25 \text{ V}, I_{E} = 0$			100	nA
Emitter-base cutoff current (Collector open)	$I_{EBO}$	$V_{EB} = 4 \text{ V}, I_C = 0$			100	nA
Forward current transfer ratio *1,2	h <sub>FE</sub>	$V_{CE} = 10 \text{ V}, I_{C} = 500 \text{ mA}$	4000		20 000	
Collector-emitter saturation voltage *1	V <sub>CE(sat)</sub>	$I_C = 500 \text{ mA}, I_B = 0.5 \text{ mA}$			2.5	V
Base-emitter saturation voltage *1	V <sub>BE(sat)</sub>	$I_C = 500 \text{ mA}, I_B = 0.5 \text{ mA}$			3.0	V

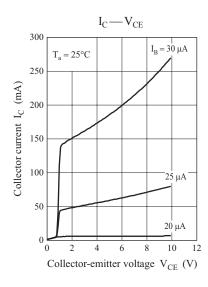
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

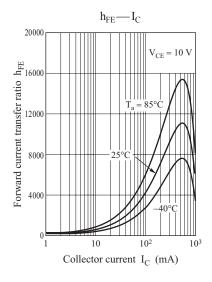
#### 2. \*1: Pulse measurement

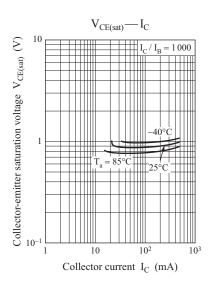
#### \*2: Rank classification

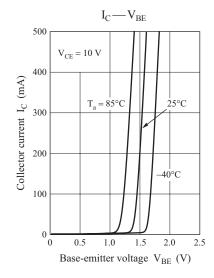
Code	Q	R
Rank	Q	R
$h_{\mathrm{FE}}$	4000 to 10000	8000 to 20000
Marking Symbol	E5Q	E5R

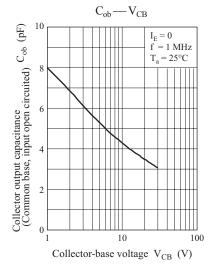


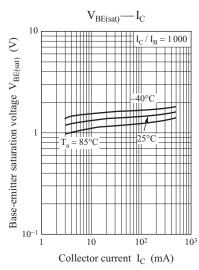








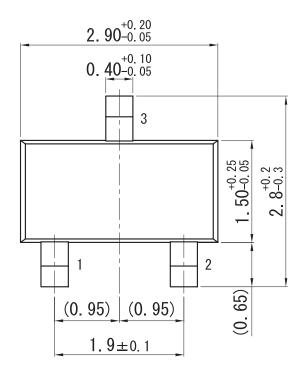


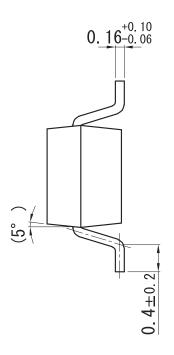


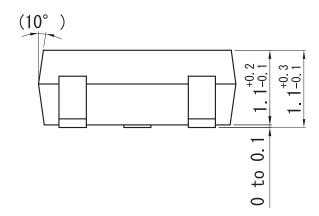
Ver. DED 2

Mini3-G3-B-B

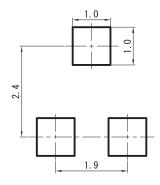
Unit: mm







#### ■ Land Pattern (Reference) (Unit: mm)



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